

ST-1KLA

The ST-1KLA is a high-sensitivity silicon phototransistor mounted in durable, hermetically sealed TO-18 metal can which provide years of reliable performance, even under demanding conditions such as use outdoors.

FEATURES

- Durable
- High reliability in demanding environments
- Two leads

APPLICATIONS

- Smoke detector
- Infrared sensors
- Optical switches
- Optical detectors

MAXIMUM RATINGS

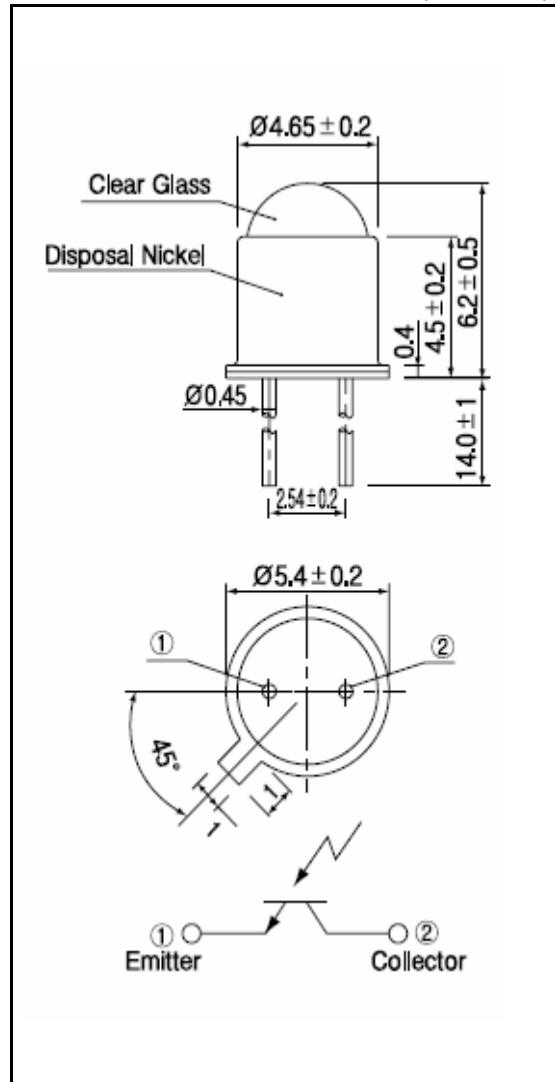
(Ta=25°C)

| Parameter | Symbol | Rating | Unit |
|-----------------------------|------------------|----------|------|
| C-E Voltage | V _{CEO} | 40 | V |
| E-C Voltage | V _{ECO} | 4 | V |
| Collector current | I _C | 50 | mA |
| Collector power dissipation | P _C | 150 | mW |
| Operating Temperature | T _{opr} | -35~+125 | °C |
| Storage Temperature | T _{stg} | -50~+150 | °C |
| Soldering temperature *1 | T _{sol} | 260 | °C |

Notes : *1. For MAX.5 seconds at the position of 2mm from the package

DIMENSION

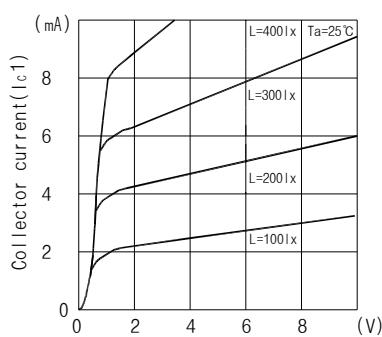
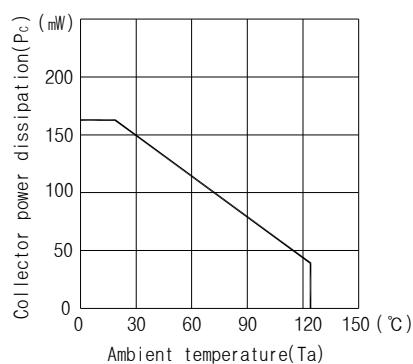
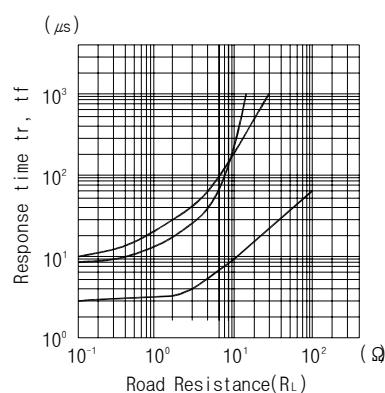
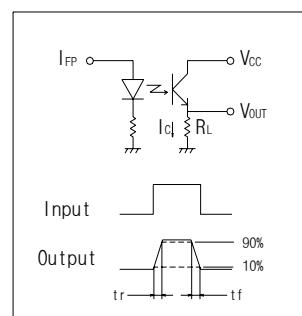
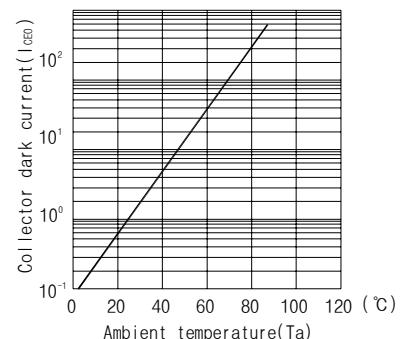
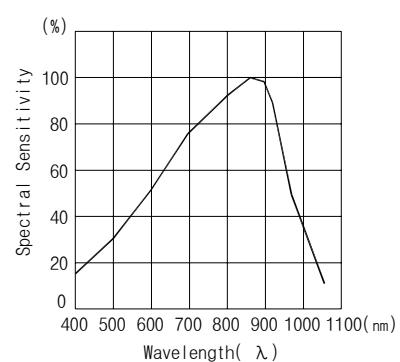
(Unit : mm)

**ELECTRO-OPTICAL CHARACTERISTICS**

(Ta=25°C, unless otherwise noted)

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit | |
|------------------------|----------------------|-----------------------------|---|-----|-----|------|----|
| Collector dark current | I _{CEO} | V _{CEO} =10V | 1 | 200 | nA | | |
| Light current | I _L | V _{CE} =10V, 200lx | 1.5 | 6.0 | 16 | mA | |
| C-E Saturation voltage | V _{CE(sat)} | I _C =5mA, 2000lx | | 0.2 | 0.4 | V | |
| Switching speeds | Rise time | tr | V _{CC} =10V, I _C =mA, R _L =100Ω | - | 8 | - | ns |
| | Fall time | tf | | - | 10 | - | ns |
| Spectral sensitivity | λ | | 500~1050 | | | nm | |
| Peak Wavelength | λ _p | | - | 880 | - | nm | |
| Half angle | ΘΔ | | - | ±15 | - | deg. | |

Notes : *2. Irradiance by CIE standard light source A (2850K tungsten lamp)

ST-1KLA**Collector Current Vs. C-E Voltage****Collector power dissipatioin Vs. Ambient Temperature****Switching time Vs. Load resistance****Switching time measurement circuit****Collector Dark Current Vs. Ambient Temperature****Relative Sensitivity Vs. Wavelength****Radiant Pattern**